U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844

JUNE 7, 2005
Project No. E-5281

	Class	Subclass	Art Unit	Ex'r Search Room No.
Abolished:	372	43-50	2881	JEF 03-C01
Established:	372	43.01, 44.01, 44.011, 45.01, 45.011, 45.012, 45.013, 46.01, 46.011-46.016, 49.01, 50.1, 50.11, 50.12, 50.121-50.124, 50.21-50.23	2881	JEF 03-C01

The following classes are impacted by this project:

Class (es): 117, 257, 359, and 438

This order includes the following:

A. CLASSIFICATION MANUAL CHANGES

B. LISTING OF PRINCIPAL SOURCE OF ESTABLISHED AND DISPOSITION OF ABOLISHED PAGES

C. CHANGES TO THE U.S. – I.P.C. CONCORDANCE

D. DEFINITION CHANGES

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844

JUNE 7, 2004
Project No. E-5281

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CLASS 372 COHERENT LIGHT GENERATORS

APRIL 2005

1 SUPERRADIANT LASER
2 FREE ELECTRON LASER
3 RAMAN LASER
4 LONG WAVELENGTH (E.G., FAR INFRARED)
5 SHORT WAVELENGTH LASER
6 OPTICAL FIBER LASER
7 THIN FILM LASER
8 LASER LOGIC SYSTEM
9 PARTICULAR BEAM CONTROL DEVICE
10 .Q-switch
11 ..Absorption type
12 ..Electro-optic
13 ..Acousto-optic
14 ..Mechanical
15 ...Rotating mirror
16 ...Rotating prism
17 ..Plural Q-switches
18 .Mode locking
19 .Mode discrimination
20 .Tuning
21 .Nonlinear device
22 ..Frequency multiplying (e.g., harmonic generator)
23 .Producing plural wavelength output
24 .Scanning
25 .Control of pulse characteristics
26 .Modulation
27 ..Polarization
28 ..Frequency
29.01 .Having particular beam control circuit component
29.011 ..Feedback circuitry
29.012 ..Power supply
29.013 ..Having particular electrode structure
29.014 ..Controlling light intensity
29.015 ..Controlling current or voltage
29.016 ..Controlling beam phase
29.02 .Optical output stabilization
29.021 ..Power
29.022 ..Cavity
29.023 ..Phase
30 ..Pulse
31 ..Amplitude
32 ..Frequency
33 PARTICULAR OPERATING COMPENSATION MEANS
34 PARTICULAR TEMPERATURE CONTROL
35 .Liquid coolant
36 .Heat sink
37 HAVING AN APPLIED MAGNETIC FIELD
38.1 PARTICULAR COMPONENT CIRCUITRY
38.01 .Having feedback circuitry
38.02 .For driving or controlling laser
38.03 .Switch (e.g., thyratron, etc.)
38.04 .Power supply
38.05 .Electrode
38.06 .Optical pumping
38.07 .Controlling current or voltage to laser
38.08 .Having noise suppression circuitry
38.09 .Having fault protection circuitry
39 PARTICULAR ACTIVE MEDIA
40 .Amorphous (e.g., glass)
41 .Insulating crystal
42 ..Utilizing color centers
* 43.01 .Semiconductor
* 44.01 ..Injection
* 44.011 ...Crystal orientation
* 45.01 ...Particular confinement layer
* 45.011 ....With strained layer
* 45.012 ....With superlattice structure
* 45.013 ....With saturable absorption layer
* 46.01 ...Particular current control structure
* 46.011 ....Transverse junction
* 46.012 ....Channeled substrate
* 46.013 ....Having oxidized region
* 46.014 ....Having air gap region
* 46.015 ....Having implant region
* 46.016 ....Disordered region
* 49.01 ...Particular coating on facet
* 50.1 ...Monolithic integrated
* 50.11 ....With diffraction grating (Bragg reflector)
* 50.12 ....Laser array
* 50.121 .....Multiple wavelength emissive
* 50.122 .....Independently addressable
* 50.123 .....Phase locked
* 50.124 .....With vertical output (surface emission)
* 50.21 ....Having photodetection means
* 50.22 ....Having an amplifier
* 50.23 ....Having lens
51 .Liquid
52 ..Chelate
53 ..Dye
54 ..Particular structural features
55 .Gas
56 ..Metal vapor
57 ..Excimer or exciplex
58 ..With means for controlling gas flow
59 ..Gas maintenance (e.g., purification, replenishment, etc.)
60 ..Including a specified gas additive
61 ..Discharge tube feature
62 ...Segmented
63 ...Backflow feature
64 ...Waveguide
65 ...Support
66 .Active media with particular shape
67 ..Disc-shaped
68 .Plural active media or active media having plural dopants
69 PARTICULAR PUMPING MEANS
70 .Pumping with optical or radiant energy
71 ..End-pumped laser
72 ..Pump cavity
73 ..High-energy particles
74 ...Electron beam
75 ..Semiconductor
76 ..Plasma
77 ..Exploding or combustible material
78 ..Heat
79 ..Solar
80 ..Excited phosphor
81 .Electrical
82 ..Inductive or capactive excitation

Title Change
* Newly Established Subclass
@ Indent Change
& Position Change

PARTICULAR PUMPING MEANS
.Electrical
83 ..Transversely excited
84 ...Traveling wave
85 ..Glow discharge
86 ..Having an auxiliary ionization means
87 ..Having particular electrode structure
88 ...Hollow electrode
89 .Chemical
90 .Gas dynamic
91 .With depopulation of lower states
92 PARTICULAR RESONANT CAVITY
93 .Folded cavity
94 ..Having a ring configuration
95 .Unstable resonator
96 .Distributed feedback
97 .Plural cavities
98 .Specified cavity component
99 ..Reflector
100 ..Prism
101 ..Lens or lens system
102 ..Grating
103 ..Window, aperture, and mask
104 ...Aerodynamic window
105 ..Birefringent material
106 ..Polarizer
107 .Mirror support or alignment structure
108 .Specified output coupling device
109 MISCELLANEOUS

****

CROSS-REFERENCE ART COLLECTIONS

****

700 OPTICAL DELAY
701 NOZZLE
702 ISOTOPE
703 OPTICAL ISOLATER
704 SUMMARY REFERENCE
705 NEAT THING

****

FOREIGN ART COLLECTIONS

****

FOR 000 CLASS-RELATED FOREIGN DOCUMENTS

Any foreign patents or non-patent literature from subclasses that have been reclassified have been transferred directly to FOR Collections listed below. These Collections contain ONLY foreign patents or non-patent literature. The parenthetical references in the Collection titles refer to the abolished subclasses from which these Collections were derived.

PARTICULAR BEAM CONTROL DEVICE (372/9)
FOR 100 .Output stabilization (372/29)
FOR 101 WITH PARTICULAR COMPONENT CIRCUITRY (372/38)
* FOR 102 .Semiconductor (372/43)
* FOR 103 ..Injection (372/44)
* FOR 104 ...Particular confinement layer (372/45)
* FOR 105 ...Particular current control structure (372/46)
* FOR 106 ....Transverse junction (372/47)
* FOR 107 ....Channeled substrate (372/48)
* FOR 108 ...Particular coating on facet (372/49)
* FOR 109 ...Monolithic integrated (372/43)

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
372/43.01	1	372/45	930
	1	372/48	41
	1	372/50	649
	3	372/47	17
	4	372/45	930
	15	372/46	657
	93	372/43	247
	100	372/43	247
372/44.01	1	372/43	247
	3	372/46	657
	9	372/44	140
	97	372/44	140
372/44.011	1	372/43	247
	1	372/43	247
	1	372/45	930
	28	372/44	140
372/45.01	1	372/50	649
	17	372/46	657
	202	372/45	930
	546	372/45	930

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
372/45.011	3	372/43	247
	8	372/45	930
	43	372/45	930
372/45.012	1	372/43	247
	1	372/46	657
	4	372/46	657
	9	372/45	930
	53	372/45	930
372/45.013	1	372/43	247
	1	372/44	140
	3	372/46	657
	4	372/46	657
	11	372/45	930
	16	372/45	930
372/46.01	1	372/43	247
	1	372/45	930
	1	372/48	41
	110	372/46	657
	378	372/46	657
372/46.011	14	372/47	17
372/46.012	38	372/48	41

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
372/46.013	1	372/44	140
	2	372/43	247
	6	372/45	930
372/46.013	8	372/46	657
	14	372/46	657
372/46.014	1	372/43	247
	24	372/46	657
372/46.015	1	372/43	247
	2	372/43	247
	2	372/45	930
	4	372/46	657
	14	372/46	657
372/46.016	1	372/45	930
	1	372/46	657
	19	372/46	657
372/49.01	1	372/48	41
	24	372/49	103
	79	372/49	103
372/50.1	1	372/45	930
	1	372/46	657
	3	372/43	247

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
	80	372/50	649
	163	372/50	649
372/50.11	1	372/44	140
	1	372/44	140
	2	372/45	930
	3	372/43	247
	3	372/46	657
	3	372/46	657
	4	372/43	247
	15	372/45	930
	17	372/50	649
	48	372/50	649
372/50.12	1	372/44	140
	2	372/43	247
	5	372/46	657
	99	372/50	649
372/50.121	1	372/46	657
	2	372/50	649
	32	372/50	649
372/50.122	2	372/43	247
	2	372/46	657

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
	2	372/50	649
	10	372/50	649
372/50.123	1	372/44	140
	1	372/46	657
	2	372/45	930
372/50.123	23	372/50	649
372/50.124	1	372/45	930
	1	372/50	649
	3	372/43	247
	13	372/46	657
	23	372/50	649
372/50.21	1	372/43	247
	1	372/45	930
	1	372/46	657
	10	372/43	247
	12	372/50	649
	61	372/50	649
372/50.22	1	372/43	247
	1	372/45	930
	1	372/46	657
	2	372/43	247

Patent and Trademark Office

CLASSIFICATION ORDER E-5281

June 7, 2005

Project No. 1844

SOURCE CLASSIFICATION(S) OF PATENTS

IN NEWLY ESTABLISHED SUBCLASSES REPORT

New Classification	Number Of ORs	Source Classification	Number Of ORs
	2	372/45	930
	3	372/46	657
	12	372/50	649
	36	372/50	649
372/50.23	1	372/45	930
	1	372/50	649
	3	372/46	657
	8	372/43	247
	24	372/50	649
372/58	1	372/50	649
438/758	1	372/46	657

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs
372/43	247	372/50.1	3
		372/43.01	93
		372/43.01	100
		372/44.01	1
		372/46.01	1
		372/50.11	3
		372/50.11	4
		372/50.12	2
		372/50.21	1
		372/50.21	10
		372/50.22	1
		372/50.22	2
		372/50.23	8
		372/44.011	1
		372/45.011	3
		372/45.012	1
		372/45.013	1
		372/46.013	2
		372/46.014	1
		372/46.015	1
		372/46.015	2
		372/50.122	2

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs
		372/50.124	3
372/44	140	372/44.01	9
		372/44.01	97
		372/50.11	1
		372/50.12	1
		372/44.011	28
		372/45.013	1
		372/46.013	1
		372/50.123	1
372/45	930	372/50.1	1
		372/43.01	1
		372/43.01	4
		372/45.01	202
		372/45.01	546
		372/46.01	1
		372/50.11	2
		372/50.11	15
		372/50.21	1
		372/50.22	1
		372/50.22	2
		372/50.23	1
		372/44.011	1
		372/45.011	8
		372/45.011	43

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs
372/45	930	372/45.012	9
		372/45.012	53
		372/45.013	11
		372/45.013	16
		372/46.013	6
		372/46.015	2
		372/46.016	1
		372/50.123	2
		372/50.124	1
372/46	657	372/50.1	1
		372/43.01	15
		372/44.01	3
		372/45.01	17
		372/46.01	110
		372/46.01	378
		372/50.11	3
		372/50.12	5
		372/50.21	1
		372/50.22	1
		372/50.22	3
		372/50.23	3
		372/45.012	1
		372/45.012	4

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs
		372/45.013	3
		372/45.013	4
		372/46.013	8
		372/46.013	14
		372/46.014	24
		372/46.015	4
		372/46.015	14
		372/46.016	1
		372/46.016	19
		372/50.121	1
		372/50.122	2
		372/50.123	1
		372/50.124	13
		438/758	1
372/47	17	372/43.01	3
		372/46.011	14
372/48	41	372/43.01	1
		372/46.01	1
		372/49.01	1
		372/46.012	38
372/49	103	372/49.01	24
		372/49.01	79
372/50	649	372/58	1

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs
372/50	649	372/50.1	80
		372/50.1	163
		372/43.01	1
		372/45.01	1
		372/50.11	17
		372/50.11	48
		372/50.12	99
		372/50.21	12
		372/50.21	61
		372/50.22	12
		372/50.22	36
		372/50.23	1
		372/50.23	24
		372/50.121	2
		372/50.121	32
		372/50.122	2
		372/50.122	10
		372/50.123	23
		372/50.124	1
		372/50.124	23

U.S. DEPARTMENT OF COMMERCE
Patent and Trademark Office

CLASSIFICATION ORDER 1844
June 7, 2004

Project No. 1844

DISPOSITION CLASSIFICATION(S) OF PATENTS FROM ABOLISHED SUBCLASSES REPORT

Source Classification	Number of ORs	New Classification	Number of ORs

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CLASSIFICATION ORDER 1844

APRIL 5, 2005
Project No. E-5281

C. CHANGES TO THE U.S. - I.P.C. CONCORDANCE

Class	Subclass	Subclass	Notation
372	43.01	H01S	5/00 3/04 3/18
	44.01	H01S	5/00
	44.011	H01S	5/00
	45.01	H01S	5/00 5/20 5/23 5/323
	45.011	H01S	5/00 3/19
	45.012	H01S	5/00 3/19
	45.013	H01S	5/00 3/19
	45.014	H01S	5/00 3/19
	46.01	H01S	5/00 3/19
	46.011	H01S	5/00 3/19
	46.012	H01S	5/00 3/19
	46.013	H01S	5/00 3/19
	46.014	H01S	5/00 3/19
	46.015	H01S	5/00 3/19

Class	Subclass	Subclass	Notation
	46.016	H01S	5/00 3/19
	49.01	H01S	5/00 3/19
	50.1	H01S	5/00 3/19
	50.11	H01S	5/00 3/19
	50.12	H01S	5/00 3/19
	50.121	H01S	5/00 3/19
	50.122	H01S	5/00 3/19
	50.123	H01S	5/00 3/19
	50.124	H01S	5/00 3/19
	50.21	H01S	5/00 3/19
	50.22	H01S	5/00 3/19
	50.23	H01S	5/00 3/19

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D. CHANGES TO THE DEFINITIONS (Project No. E-5281)

CLASS 117 – SINGLE-CRYSTAL, ORIENTED–CRYSTAL, AND EPITAXY GROWTH PROCESSES; NON-COATING APPARATUS THEREFOR

Definitions Modified (Place modifications in numerical sequence, where applicable):

Class Definition: In Section IV, References to Other Classes:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, appropriate subclasses for art named devices (e.g., lasers), especially subclasses 43.01+ for semiconductor lasers. (B., Selected Notes to Article, Material, Composition, Device, and Product Classes.)

D. CHANGES TO THE DEFINITIONS (Project No. E-5281)

CLASS 257 – ACTIVE SOLID-STATE DEVICES (E.G.,TRANSISTORS, SOLID-STATE DIODES)

Definitions Modified (Place modifications in numerical sequence, where applicable):

Subclass 9: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, subclasses 43.01+ for semiconductor lasers which may contain thin layer devices of this type for producing coherent light.

Subclass 13: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, subclasses 43.01+ for coherent semiconductor light generators.

Subclass 183: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, subclasses 43 through 50 for semiconductor lasers which may contain heterojunctions.

D. CHANGES TO THE DEFINITIONS (Project No. E-5281)

CLASS 359 – OPTICAL: SYSTEMS AND ELEMENTS

Definitions Modified (Place modifications in numerical sequence, where applicable):

Subclass 344: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, subclasses 43.01+ for a semiconductor active medium which is not used for amplification of a light beam input.

D. CHANGES TO THE DEFINITIONS (Project No. E-5281)

CLASS 372 – COHERENT LIGHT GENERATORS

Definitions Abolished

Subclasses

43 – 50

DEFINITIONS ESTABLISHED (Place established subclasses in numerical sequence.):

43.01 Semiconductor:

Subject matter under subclass 39 wherein the active media of the coherent light generator or laser is a semiconductor.

44.01 Injection:

Subject matter under subclass 43.01 wherein the semiconductor includes a p-n junction which converts forward-bias electrical input directly into coherent optical output power via a process of stimulating emmission in the region near the junction.

SEARCH CLASS:

257, Active Solid-State Devices (e.g., Transistors, Solid-State Diodes), subclass 13 , 79 through 103, and 918 for incoherent light emitting injection luminescent devices, and subclasses 80 through 85 for semiconductor light emitting sources combined with semiconductor light responsive devices.

438, Semiconductor Device Manufacturing: Process, subclasses 22+ for methods of making radiation emissive devices of the semiconductor barrier layer type.

44.011 Crystal orientation:

Subject matter under subclass 44.01 wherein the semiconductor includes a layer that has a predetermined angle with respect to an edge or a facet at which a crystal is sliced.

45.01 Particular confinement layer:

Subject matter under subclass 44.01 wherein the semiconductor includes a layer specifically designed to hold carrier and/or radiation within a boundary.

45.011 With strained layer:

Subject matter under subclass 45.01 wherein the layer has a lattice constant different from that of the semiconductor substrate.

45.012 With superlattice structure:

Subject matter under subclass 45.01 wherein the layer consists of a series of alternating epitaxial layers of two types of material, each layer having a thickness below a critical thickness.

SEARCH CLASS:

257, Active Solid-State Devices (e.g., Transistor, Solid-State Diodes), subclass 15+ for Quantum well supperlattice.

45.013 With saturable absorption layer:

Subject matter under subclass 45.01wherein the layer has an energy bandgap less than that of the semiconductor.

46.01 Particular current control structure:

Subject matter under subclass 44.01wherein the p-n junction of the semiconductor is specifically designed to control a current flow in an active region.

46.011 Transverse junction:

Subject matter under subclass 46.01 wherein the p.n junction is set across the layer of the active region.

46.012 Channeled substrate:

Subject matter under subclass 46.01wherein the substrate of the semiconductor is cut in grooves.

46.013 Having oxidized region:

Subject matter under subclass 46.01 wherein the particular current control structure includes an area that is oxidized.

(1) Note: An area that is oxidized when it is combined with oxygen or it is changed from a lower to a higher positive valence.

46.014 Having air gap region:

Subject matter under subclass 46.01wherein the p-n junction structure includes a space between layers.

46.015 Having implant region:

Subject matter under subclass 46.01 wherein the p-n junction structure includes a layer is created by implantation of ions.

46.016 Disordered region:

Subject matter under subclass 46.01 wherein the p-n junction include layers that are structured in different orders or positions.

49.01 Particular coating on facet:

Subject matter under subclass 44.01 wherein the semiconductor has a specified layer covered on at least one facet.

50.1 Monolithic integrated:

Subject matter under subclass 44.01wherein electrical elements or circuits formed within a semiconductor substrate.

50.11 With diffraction grating (Bragg reflector):

Subject matter under subclass 50.1 wherein the semiconductor includes a series of very fine, closely spaced parallel slits, or of very narrow, parallel reflecting surfaces to produce a succession of spectra when light is incident thereon at a specific angle.

SEARCH CLASS:

359, Optic Systems and Elements, subclass 563 for diffraction grating.

385, Optical Waveguides, subclass 10 for electro-optic diffraction grating

50.12 Laser array:

Subject matter under subclass 50.1 including a group of many similar, basic, complex, or integrated devices without separate enclosures.

50.121 Multiple wavelength emissive:

Subject matter under subclass 50.12 wherein a light output of the laser array has a plurality of discrete wavelengths.

50.122 Independently addressable

Subject matter under subclass 50.12, wherein the integrated devices of the laser array are separately controlled.

50.123 Phase locked:

Subject matter under subclass 50.12, wherein a plurality of active regions of the laser array are sufficiently close to each other that light from each active region is coupled to the light from the adjacent active region.

50.124 With vertical output (surface emission):

Subject matter under subclass 50.1 wherein a light output of the laser array is perpendicular to a surface of the semiconductor.

50.21 Having photodetection means:

Subject matter under subclass 50.1 including a device for monitoring a light emitted from the semiconductor laser.

50.22 Having an amplifier:

Subject matter under subclass 50.1 wherein the semiconductor device includes a device that produces as an output an enlarged reproduction of the essential features of its inputs.

SEARCH CLASS:

359, Optic: Systems and Elements, subclass 333+ for optical amplifier.

50.23 Having lens:

Subject matter under subclass 50.1 wherein the semiconductor device includes an optical device made of glass or a piece of transparent material which focuses light to form an image.

SEARCH CLASS:

359, Optic: Systems and Elements, subclass 362+ for compound lens system.

FOREIGN ART COLLECTIONS

The definitions below correspond to abolished subclasses from which these collections were formed. See the Foreign Art Collection schedule of this class for specific correspondences. [Note: The titles and definitions for indented art collections include all the details of the one(s) that are hierarchically superior.]

FOR 102 Semiconductor:

This subclass is indented under subclass 39. Foreign art collection wherein the active media is a semiconductor.

FOR 103 **Injection:**

This subclass is indented under subclass 43. Foreign art collection wherein the laser is a p.n junction semiconductor device which converts forward-bias electrical input directly into coherent optical output power via a process of stimulated emission in the region near the junction.

.

FOR 104 **Particular confinement layer:**

This subclass is indented under subclass 44. Foreign art collection wherein there is present a layer specifically designed to provide for carrier and/ or radiation confinement.

FOR 105 **Particular current control structure**

:

This subclass is indented under subclass 44. Foreign art collection wherein there is a means which is specifically designed to provide for control of the current flow in the area of the active region.

FOR 106 **Transverse junction:**

:

This subclass is indented under subclass 46. Foreign art collection wherein the p.n junction is transverse to the active layer.

FOR 107 **Channeled substrate**

:

This subclass is indented under subclass 46. Foreign art collection wherein the substrate has a channel in the substrate region adjacent the active region.

FOR 108 **Particular coating on facet:**

This subclass is indented under subclass 44. Foreign art collection having a specified coating on at least one facet.

FOR 109 **Monolithic integrated:**

This subclass is indented under subclass 44. Foreign art collection wherein the laser is monolithically integrated with another laser or with other semiconductor devices which form an integral part of the laser.

D. CHANGES TO THE DEFINITIONS (Project No. E-5281)

CLASS 438 – SEMICONDUCTOR DEVICE MANUFACTURING: PROCESS

Definitions Modified (Place modifications in numerical sequence, where applicable):

Subclass 22: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, for coherent light emissive devices, in particular subclasses 43.01+ for a semiconductive laser device and subclass 75 for semiconductor optical laser pump devices.

Subclass 24: Under See or Search Class:

Delete:

The entire search reference to Class 372.

Insert:

372, Coherent Light Generators, for coherent light emissive devices, in particular subclasses 43.01+ for a semiconductive laser device and subclass 75 for semiconductor optical laser pump devices.